### Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

#### **General Description**

The MAX25220/MAX25221/MAX25221B are 4-channel TFT-LCD power ICs that provide symmetrical positive AVDD and negative NAVDD supplies as well as  $VG_{ON}$  and  $VG_{OFF}$  gate supplies. In addition, a VCOM buffer with output voltage range above and below ground and a temperature measurement block are integrated (MAX25221/B).

The devices contain non-volatile memory so that the values of all outputs can be calibrated for the lifetime of the device (maximum five times).

Programming is carried out using the built-in I<sup>2</sup>C interface, which can also be used to read back diagnostic information. A stand-alone mode is also available.

The temperature sensor interface block measures the temperature optionally allowing the VCOM output voltage to be adjusted depending on the measured temperature.

The MAX25220/MAX25221/MAX25221B are available in a TQFN package and operate in the -40 to 125°C temperature range.

### **Applications**

- Infotainment Displays
- Central Information Displays
- Instrument Clusters

#### **Benefits and Features**

- High Integration
  - Synchronous Boost Provides AVDD of 4.2V to 10.5V at up to 200mA
  - NAVDD Inverter Output at up to -200mA
  - 15mA VG<sub>ON</sub> Output (7.6V to 20.2V) from 3x Regulated Charge Pump
  - VG<sub>OFF</sub> (-18.2V to -5.6V) from Regulated Charge Pump at up to -15mA (charge-pump doubler)
  - Controlled Sequencing during Power-On and Power-Off of All Rails
  - VCOM Output Range +1V to -2.49V in 6.83mV Steps (MAX25221)
  - NTC Input for Temperature Measurement/ Compensation (MAX25221)
- Low EMI
  - 420kHz/2.1MHz Switching Frequency with Spread Spectrum
- I<sup>2</sup>C Control/Diagnostic Interface with FLTB (Interrupt) Output
  - UV diagnostics on All Outputs
- Versatile
  - Non-Volatile Output Voltage Settings on AVDD/ NAVDD, VG<sub>ON</sub>, VG<sub>OFF</sub>, VCOM, and Sequencing
  - Supports Stand-Alone Operation Mode after Programming
  - Compact 5mm x 5mm TQFN32 Package
- AECQ100 Grade 1

Ordering Information appears at end of datasheet.



# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### Simplified Block Diagram



# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

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# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Absolute Maximum Ratings**

IN, INN to GND	-0.3V to +6V	VCOMN to GND	V18 - 6V to V18 + 0.3V
IN to INN		PGVDD, FC1-, FC2-, DN to GND	0.3V to HVINP + 0.3V
V18 to GND	0.3V to +2.2V	FC1+ to GND	0.3V to PGVDD + 0.3V
HVINP to GND	0.3V to 16V	FC2+ TO FC1+	0.3V to +22V
LXP, AVDD to GND		VG <sub>ON</sub> to FC2+	0.3V to +22V
BST to GND		FC2+, VG <sub>ON</sub> to GND	0.3V to +24V
BST to LXP	0.3V to +2.2V	EN, FLTB, SCL, SDA to GND	0.3V to +6V
LXN to INN	22V to +0.3V	ADD, TEMP, R <sub>REF</sub> to GND	0.3V to V18 + 0.3V
PGND, CPGND, DGND to GND	0.3V to +0.3V	V <sub>PROG</sub> to GND	0.3V to +14V
VCB to GND	V18 - 22V to V18 + 0.3V	Continuous Power Dissipation (Multil	ayer Board) ( $T_A = +70^{\circ}C$ ,
VGOFF, NAVDD to GND	IN - 22V to IN + 0.3V	derate 21.3mW/°C above +70°C)	
VCOM to GND	VCOMN - 0.3V to IN + 0.3V	Operating Temperature Range	40°C to 125°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **Package Information**

#### TQFN

Package Code	T3255+6C			
Outline Number	<u>21-0140</u>			
Land Pattern Number	<u>90-0603</u>			
Thermal Resistance, Single-Layer Board:				
Junction to Ambient $(\theta_{JA})$	47°C/W			
Junction to Case $(\theta_{JC})$	3°C/W			
Thermal Resistance, Four-Layer Board:				
Junction to Ambient ( $\theta_{JA}$ )	36°C/W			
Junction to Case $(\theta_{JC})$	3°C/W			

#### **TQFN-SW**

Package Code	T3255Y+6C			
Outline Number	<u>21-100041</u>			
Land Pattern Number	<u>90-100066</u>			
Thermal Resistance, Single-Layer Board:				
Junction to Ambient (θ <sub>JA</sub> )	47°C/W			
Junction to Case $(\theta_{JC})$	3°C/W			
Thermal Resistance, Four-Layer Board:				
Junction to Ambient ( $\theta_{JA}$ )	36°C/W			
Junction to Case ( $\theta_{JC}$ )	3°C/W			

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <u>www.maximintegrated.com/thermal-tutorial</u>.

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Electrical Characteristics**

(V<sub>IN</sub> = 3.3V, V<sub>INN</sub> = 3.3V, Limits are 100% guaranteed between T<sub>A</sub> = -40°C and T<sub>A</sub> = +125°C. )

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
INPUT SUPPLY	1					
IN Voltage Range			2.65		5.5	V
IN UVLO Threshold	IN_UVLO_R	Rising	2.4	2.5	2.57	V
IN UVLO Hysteresis	IN_UVLO_HY S			100		mV
IN Shutdown Current	IIN SHDN	EN = GND, V <sub>IN</sub> = 3.3V, T <sub>A</sub> = 25°C		7	12	μA
IN Quiescent Current	I <sub>IN Q</sub>	V <sub>EN</sub> = V <sub>IN</sub> = 3.3V, no switching.		1.5	2.5	mA
V18 REGULATOR		1	1			
V18 Output Voltage			1.72	1.8	1.88	V
V18 Current Limit			60			mA
V18 Undervoltage Lockout		V18 rising	1.6	1.65	1.7	V
V18 Undervoltage Hysteresis				150		mV
OSCILLATOR	•		1			
	<sup>f</sup> вооsтн	f <sub>SW</sub> bit = 0, dither disabled. Switching frequency for boost, inverter, and charge pumps.	1950	2100	2250	
Operating Frequency	fboostl.	f <sub>SW</sub> bit = 1, dither disabled. Switching frequency for boost, inverter, and charge pumps.	385	420	455	KHZ
Frequency Dither	fBOOSTD			±6		%
BOOST REGULATOR	_					
HVINP Output Voltage Range	V <sub>HVINP</sub>		V <sub>IN</sub> + 1		10.5	V
AVDD Output Voltage Range			4.2		10.5	V
AVDD Adjustment Step Size				0.1		v
AVDD Output Regulation	V <sub>AVDD</sub>	avdd[5:0] = 0x1A, full load current and input voltage range	6.664	6.8	6.936	v
Oscillator Maximum		420kHz switching frequency	87	88.5	90	0/
Duty Cycle		2.1MHz switching frequency	84	87	90	<b>%</b>
Low-Side Switch On- Resistance	LXP_RON_LS	I <sub>LXP</sub> = 0.1A		0.1	0.2	Ω
Synchronous Rectifier On-Resistance				0.1	0.2	Ω
Synchronous Rectifier Zero-Crossing Threshold	ZX_TH			70		mA
LXP Leakage Current	LXP_L_LEAK	V <sub>EN</sub> = 0V, V <sub>LXP</sub> = 10.5V			20	μA
LXP Current Limit	ILIMPH	Duty cycle = 50%	1.7	2	2.3	A

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Electrical Characteristics (continued)**

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS		
Soft-Start Period	t <sub>BOOST_SS</sub>	Current-limit ramp		5		ms		
INVERTING REGULATOR								
Oscillator Maximum		2.1MHz switching frequency	92	95		0/		
Duty Cycle	INV_MAXDC	420kHz switching frequency	88	90				
V <sub>AVDD</sub> + V <sub>NAVDD</sub> Regulation Voltage	V <sub>NAVDD_</sub> AVD D_REG	$V_{INN}$ = 2.65V to 5.5V, $V_{AVDD}$ = 6.8V, 1mA < I <sub>NAVDD</sub> < 200mA, I <sub>AVDD</sub> = same load as NAVDD	-34	0	34	mV		
LXN On-Resistance	LXN_RON	INN to LXN, I <sub>LXN</sub> = 0.1A		0.25	0.5	Ω		
LXN Leakage Current	LXN_LEAK	V <sub>IN</sub> = 3.6V, V <sub>LXN</sub> = V <sub>NAVDD</sub> = -6.8V, T <sub>A</sub> = +25°C			20	μA		
LXN Current Limit	I <sub>LIMNH</sub>	Duty cycle = 80%	1.55	1.9	2.25	A		
Soft-Start Period	t <sub>INV_SS</sub>	Current-limit ramp		5		ms		
NAVDD Discharge Resistance				2		kΩ		
POSITIVE CHARGE-PUN	IP REGULATOR	2						
VG <sub>ON</sub> Threshold for Charge-Pump Switching Enable				V <sub>HVINP</sub> - 0.8		V		
FC1-, FC2- Switches Current Limit, High-side			90	120		mA		
FC1-, FC2- Switches Current Limit, Low-side			72	100		mA		
FC1-, FC2- to CPGND On-Resistance				4	6.5	Ω		
FC1-, FC2- to HVINP On-Resistance				6	10.5	Ω		
FC2+ to PGVDD, FC1+ to FC2+ and VG <sub>ON</sub> to FC1+ Switches On- Resistance				2.5	4.5	Ω		
VG <sub>ON</sub> Voltage Range, I <sup>2</sup> C Mode			7.6		20.2	V		
VG <sub>ON</sub> Adjustment Step Size, I <sup>2</sup> C Mode				0.2		V		
VG <sub>ON</sub> Output Voltage	V <sub>VGON</sub>	vgon[5:0] = 0x16, full load current and $V_{HVINP} > 5V$ , charge-pump tripler	11.7	12	12.3	V		
VG <sub>ON</sub> Discharge Resistance			2.2	3	3.8	kΩ		
NEGATIVE CHARGE-PU	MP REGULATO	R						
DN Current Limit			75	100		mA		
VG <sub>OFF</sub> Voltage Range, I <sup>2</sup> C Mode			-18.2		-5.6	v		

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Electrical Characteristics (continued)**

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
VG <sub>OFF</sub> Adjustment Step Size, I <sup>2</sup> C Mode				0.2		V
VG <sub>OFF</sub> Output-Voltage Accuracy		vgoff[5:0] = 0x16, full load current and input voltage range, 420kHz operation.	-10.3	-10	-9.7	V
DN On-Resistance, High-Side				6	10	Ω
DN On-Resistance, Low-Side		I <sub>DN</sub> = -10mA		3.5	6.5	Ω
VG <sub>OFF</sub> Discharge Current				1.5		mA
SEQUENCE SWITCHES						
AVDD ON Resistance	R <sub>ONAVDD</sub>	Between HVINP and AVDD, I <sub>AVDD</sub> = 200mA		0.5	1	Ω
AVDD Current Limit	ILIM <sub>POS</sub>		300		600	mA
AVDD Discharge Resistance				1.2		kΩ
PGVDD On resistance		(HVINP-PGVDD), I <sub>PGVDD</sub> = 3mA		6	9	Ω
PGVDD Current Limit		Expires when PGVDD charging is completed	80	100		mA
FAULT PROTECTION						
Fault Timeout		tfault[1:0] = 10		60		ms
Fault Retry Time		tretry[1:0] = 10 or 11		1.9		S
FLTB Output Frequency		Stand-alone mode only	0.88	1	1.12	kHz
FLTB Output Duty Cycle, VG <sub>ON</sub> or VG <sub>OFF</sub> Fault		Stand-alone mode only		75		%
FLTB Output Duty Cycle with AVDD, NAVDD or HVINP Fault		Stand-alone mode only		50		%
FLTB Output Duty Cycle, VCOM Fault		Stand-alone mode only		25		%
AVDD Undervoltage Fault Threshold		Relative measurement between HVINP and AVDD	80	85	90	%
AVDD Short-Circuit Fault Threshold		Relative measurement between HVINP and AVDD	35	40	45	%
NAVDD Undervoltage Fault Threshold		Measured with respect to AVDD	80	85	90	%
NAVDD Short-Circuit Fault Threshold		Measured with respect to AVDD	35	40	45	%
VG <sub>ON</sub> Undervoltage Fault Threshold		Of set value	80	85	90	%
VG <sub>ON</sub> Short-Circuit Fault Threshold		VG <sub>ON</sub> Falling		V <sub>HVINP</sub> - 1.1		V

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Electrical Characteristics (continued)**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
VG <sub>OFF</sub> Undervoltage Fault Threshold		Of set value	80	85	90	%
VG <sub>OFF</sub> Short-Circuit Fault Threshold			35	40	45	%
Short-Circuit and Overload Fault Delay				10		μs
VCOM BUFFER						
VCOMN Output Voltage		I <sub>VCOM</sub> = 120mA, V <sub>NAVDD</sub> = -10.5V		-3.5	-3.2	V
VCB Output Current			5	12	21	mA
VCOM Output Current Limit, Sinking		Dynamic output current, t < t <sub>FAULT</sub>	120	200	300	mA
VCOM Output Current Limit, Sourcing	ILIMCOMP	Dynamic output current, t < t <sub>FAULT</sub>	120	200	300	mA
VCOM Overcurrent Detection Threshold			60	70	85	of I <sub>LIMCOMP</sub>
VCOM Offset Voltage, Complete Range		$V_{VCOM}$ = -2.49V and $V_{VCOM}$ = +1V, no load	-20		+20	mV
VCOM Offset Voltage, 25°C		T <sub>A</sub> = 25°C, VCOM = -0.5V	-6		+6	mV
VCOM Offset Voltage		VCOM = -0.5V	-10		+10	mV
VCOM Output Voltage Range		Temperature compensation disabled	-2.49		1	V
VCOM DAC Step Size				6.83		mV
VCOM Buffer Slew Rate		C <sub>VCOM</sub> = 10nF, VCOM from -2.49V to +1V		0.72		V/µs
VCOM Fault Threshold		Deviation from set voltage		<u>+</u> 0.25		V
VCOM Fault Detection Filter Time		tfault[1:0] = 10		60		ms
VCOM Discharge Resistance		to GND	9	14	22	kΩ
R <sub>REF</sub> INPUT	·		·			·
R <sub>REF</sub> Input Voltage Range			0		1.25	V
R <sub>REF</sub> ADC Resolution				4.88		mV
R <sub>REF</sub> Conversion Rate				128		kHz
TEMP Voltage	V <sub>TEMP</sub>	I <sub>TEMP</sub> = 10 to 500μA		625		mV
TEMP Current Mirror Gain		I <sub>TEMP</sub> = 10 to 500μA		1		μΑ/μΑ
Internal Temperature Sensor Voltage		T <sub>A</sub> = 25°C		620		mV
R <sub>REF</sub> DAC Offset				5		mV

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Electrical Characteristics (continued)**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
R <sub>REF</sub> DAC Full-Scale Error				5		mV	
R <sub>REF</sub> DAC Gain Error			-0.4		+0.4	%	
R <sub>REF</sub> DAC Differential Non-linearity				0.5		LSB	
R <sub>REF</sub> DAC Integral Non- Linearity				0.5		LSB	
LOGIC INPUTS and OUTPUTS (EN, SCL, ADD, SDA)							
EN Glitch Filter	EN_BLK			10		μs	
EN Minimum Low Time For Reset		C <sub>V18</sub> = 1uF	1			ms	
EN Input Logic-High			1.22			V	
EN Input Logic-Low					0.6	V	
ADD Input Logic-High			1.22			V	
ADD Input Logic-Low					0.66	V	
ADD Input Pulldown Current				10	12	μΑ	
SCL, SDA Input, Logic- High			1.22			V	
SCL, SDA Input, Logic- Low					0.6	V	
SCL Input Leakage Current			-1		+1	μA	
FLTB, SDA Output Low Voltage	V <sub>OL</sub>	Sinking 5mA			0.4	v	
FLTB, SDA Output Leakage Current	ILEAK	5.5V	-1		+1	μA	
PROGRAMMING VOLTA	GE						
V <sub>PROG</sub> Voltage			8.2	8.5	8.8	V	
V <sub>PROG</sub> Voltage Undervoltage Threshold		V <sub>PROG</sub> rising		8	8.2	v	
V <sub>PROG</sub> Voltage Overvoltage Threshold		V <sub>PROG</sub> falling	8.8	9		V	
VPROG Input Current		During NV programming, T <sub>A</sub> = 25°C		9	25	mA	
NV Programming Time				16	20	ms	
THERMAL SHUTDOWN	·	•					
Thermal Warning Threshold				125		°C	
Thermal-Shutdown Threshold	T <sub>SHDN</sub>			160		°C	
Thermal-Shutdown Hysteresis	T <sub>SHDN_HYS</sub>			15		°C	

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Electrical Characteristics (continued)**

(V\_IN = 3.3V, V\_INN = 3.3V, Limits are 100% guaranteed between T\_A = -40°C and T\_A = +125°C. )

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS				
I <sup>2</sup> C INTERFACE	<sup>2</sup> C INTERFACE									
Clock Frequency	f <sub>SCL</sub>				0.4	MHz				
Hold Time (Repeated) START	<sup>t</sup> HD:STA		600			ns				
SCL Low Time	t <sub>LOW</sub>		1300			ns				
SCL High Time	thigh		600			ns				
Setup Time (Repeated) START	<sup>t</sup> SU:STA		600			ns				
Data Hold Time	thd:dat		0			ns				
Data Setup Time	<sup>t</sup> SU:DAT		100			ns				
Setup Time for STOP Condition	tsu:sto		600			ns				
Spike Suppression				50		ns				

Note 1: Limits are 100% tested at T<sub>A</sub> = +25°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Typical Operating Characteristics**

(V<sub>IN</sub> = +3.3V,  $F_{SW}$  = 2.1MHz,  $T_A$  = +25 C unless otherwise noted.)











BOOST REGULATOR EFFICIENCY

LOAD CURRENT (mA)

(...= 3.3)

FFICIENCY (%)

0.5

-0.0

-0.1

ERROR (%)













# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Typical Operating Characteristics (continued)**

(V<sub>IN</sub> = +3.3V,  $F_{SW}$  = 2.1MHz,  $T_A$  = +25 C unless otherwise noted.)

















# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Pin Configurations**

#### MAX25220



# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

#### MAX25221/B



### **Pin Description**

Р	IN		FUNCTION
MAX25220	MAX25221/B	NAME	FUNCTION
1	1	V <sub>PROG</sub>	Programming Voltage. Apply a voltage of 8.5V to this pin during the programming of non-volatile registers. Connect to GND through a resistor during normal operation.
2	2	LXN	DC-DC Inverting Converter Inductor/Diode Connection.
3	3	INN	Inverting Converter Input. Connect $10\mu$ F + $0.1\mu$ F ceramic capacitors from this pin to ground for proper operation.
4	—	IC	Internally connected. Leave this pin open.
—	4	VCB	Drive Output for External npn Pass Transistor for VCOMN regulator. Connect to the base of the external npn transistor.
5	—	IC	Internally Connected. Leave this pin open.
	5	VCOM	Output of VCOM amplifier.
6	—	IC	Internally Connected. Connect this pin to GND.
	6	VCOMN	Negative Supply for VCOM Buffer. Connect a ceramic capacitor of at least 1µF from VCOMN to GND.
7	7	IN	Supply Connection for Display Bias Circuitry. Bypass IN with local $10\mu F$ and $0.1\mu F$ capacitors.

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Pin Description (continued)**

P	IN	NAME	FUNCTION
MAX25220	MAX25221/B	NAME	FUNCTION
8	8	EN	Enable Input Pin. When EN is low, the device is in shutdown. When EN is taken high, the device is active. In stand-alone mode, the outputs are turned on in the stored sequence when EN goes high.
9	9	ADD	Device Address Select pin. Connect to GND or V18 to Select the Device $I^2C$ Address. See the $I^2C$ address table. To use stand-alone mode (without $I^2C$ ) leave the ADD pin open. In this mode, the device turns on all outputs in the programmed sequence when EN is taken high.
10	10	V18	Output of Internal 1.8V Regulator. Connect a 1µF capacitor from V18 to GND.
11	11	GND	Ground Connection
12	12	BST	Bootstrap Capacitor Connection for Synchronous Rectifier Driver. Connect a $0.1\mu$ F ceramic capacitor between BST and LXP.
13	13	PGND	Ground Connection for Boost Switching Device and VCOM Buffer. Connect to GND using a low-impedance trace.
14	14	LXP	Switching Node of Boost Converter. Connect the boost inductor between LXP and IN.
15	15	HVINP	Boost Output and Input to Positive and Negative Charge-Pump Drivers. Bypass HVINP with a $10\mu$ F output capacitor placed close to the pin.
16	16	AVDD	Switched Output of Boost Converter. Connect a bypass capacitor of value 2.2µF from AVDD to PGND.
17	17	PGVDD	Supply Voltage for Positive Charge Pump. PGVDD is connected to HVINP by means of an internal switch when the positive charge pump is enabled. Bypass PGVDD with a ceramic capacitor of $1\mu$ F to GND.
18	18	FC2+	Positive Connection for Second Flying Capacitor. Connect a 22nF capacitor from FC2- to FC2+.
19	19	FC2-	Negative Connection for Second Flying Capacitor. Connect a 22nF capacitor from FC2- to FC2+.
20	20	FC1+	Positive Connection for First Flying Capacitor. Connect a 22nF capacitor from FC1- to FC1+.
21	21	FC1-	Negative Connection for First Flying Capacitor. Connect a 22nF capacitor from FC1- to FC1+.
22	22	VG <sub>ON</sub>	Output of Positive Charge-Pump Block. Connect a $1\mu\text{F}$ capacitor from $\text{VG}_{\text{ON}}$ to GND.
23	23	CPGND	Ground Connection for Charge Pumps.
24	24	VG <sub>OFF</sub>	Output of Negative Charge-Pump Block. Connect a $1\mu\text{F}$ capacitor from this pin to GND.
25	25	DN	Negative Charge-Pump Push-Pull Drive Output.
26	26	SDA	Bidirectional I <sup>2</sup> C Data Pin.
27	27	SCL	I <sup>2</sup> C Clock Pin.
28	28	FLTB	Open-Drain, Active-Low Fault Output. Connect a pullup resistor from FLTB to a logic supply $\leq 5V$ . In stand-alone mode, the duty cycle of the FLTB pin indicates an error condition, if present (see <u>Table 4</u> ). When the serial interface is used, FLTB is either a 0 (indicating data to be read from the internal registers) or a 1.
29	_	IC	Internally Connected. Leave this pin open.

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Pin Description (continued)**

PIN		NAME	FUNCTION					
MAX25220	MAX25221/B	NAME	FUNCTION					
_	29	R <sub>REF</sub>	Reference Resistor Pin. When using the temperature compensation function, connect a resistor from $R_{REF}$ to GND. If unused, leave $R_{REF}$ unconnected.					
30	—	IC	Internally Connected. Leave this pin open.					
_	30	TEMP	Temperature Sensor Pin. When using the temperature compensation function, connect an NTC from TEMP to GND. If unused, leave TEMP unconnected.					
31	31	DGND	Logic Ground.					
32	32	NAVDD	Negative Source-Driver Output Voltage. Connect ceramic capacitors of value $0.1\mu F$ and $10\mu F$ from this pin to GND with the smallest capacitor closest to the pin.					

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Functional Diagrams**

#### MAX25220



# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Functional Diagrams (continued)**

#### MAX25221/B



### **Detailed Description**

The MAX25220/MAX25221/MAX25221B are 4-channel TFT-LCD power ICs that provide symmetrical positive AVDD and negative NAVDD supplies as well as  $VG_{ON}$  and  $V_{GOFF}$  gate supplies. In addition, a VCOM buffer with output voltage range above and below ground and a temperature-measurement block are integrated in the MAX25221 and MAX25221B.

The devices contain non-volatile memory so that the values of all outputs can be calibrated for the lifetime of the device.

Programming is carried out using the built-in I<sup>2</sup>C interface, which can also be used to read back diagnostic information. Operation in stand-alone mode is also possible.

The temperature-sensor interface block in the MAX25221 and MAX25221B determines the temperature by measuring the voltage on the  $R_{REF}$  pin when a temperature-sensitive component, such as an NTC, is connected to TEMP. The VCOM output voltage can be adjusted as a function of the measured temperature.

#### Power-Up state

When power is applied, the MAX25220/1 are in low-quiescent-current mode until the EN pin is taken high. When EN is taken high (if the device supply voltage on IN exceeds the undervoltage lockout voltage of 2.5V) the 1.8V regulator is turned on and the device is functional after a delay of 1ms. Subsequent operation depends on the device configuration and type as follows:

### Table 1. DEVICE BEHAVIOR AFTER START-UP

DEVICE	ADD = 0	ADD PIN FLOATING	ADD = V18
MAX25220/ 1	Outputs turned on when start bit in register REG_CTRL is written to 1.	Outputs turned on immediately when EN high.	Outputs turned on when start bit in register REG_CTRL is written to 1.
MAX25221B	Outputs turned on immediately when EN high.	Outputs turned on immediately when EN high.	Outputs turned on immediately when EN high.

If the non-volatile memory has been written to previously the stored values are read and the outputs are turned on in the programmed sequence. If the device has not been programmed previously it powers up with the default voltages of 6.8V (AVDD), 12V (VG<sub>ON</sub>) and -10V (VG<sub>OFF</sub>).

When I<sup>2</sup>C is used, all values can be programmed and the outputs turned on using the start bit in the REG\_CTRL register. The values can subsequently be stored in non-volatile memory using the burn\_otp command, if required.

If at any time the internal 1.8V regulator is out of range, the v18oor bit is set in register FAULT2 and the FLTB pin is asserted low, assuming the device is being used in I<sup>2</sup>C mode. No other action is taken unless the V18 voltage is below its undervoltage lockout level.

#### Switching Frequency

The switching frequency of the boost and inverting converters and the charge pumps is set using the  $f_{SW}$  bit in register CONFIG. When  $f_{SW}$  is 0, the switching frequency is 2.1MHz. When  $f_{SW}$  is set to 1, the switching frequency is 420kHz. The switching frequency can have spread-spectrum applied to improve EMI performance using the en\_ss bit in register CONFIG.

#### Stand-Alone Operation

Stand-alone operation is used when the device has already been programmed and should start up with the preprogrammed values when power is applied and the EN pin taken high. In stand-alone mode, leave the ADD pin unconnected.

#### I<sup>2</sup>C Read-Only Mode

The MAX25221B starts up immediately with the pre-programmed values when power is applied and the EN pin taken high. If the ADD pin is connected to V18 the I<sup>2</sup>C interface is in read-only mode and can only be used to read the device registers, writing is not possible. The 7-bit I2C address of the device is 0x29 (0x53 when the read bit is added) in this

mode.

#### **Source Driver Power Supplies**

The source-driver power supplies consist of a boost converter with output switch and an inverting buck-boost converter that generate up to +10.5V maximum and down to -10.5V minimum, respectively, and can deliver up to 200mA on the positive regulator and -200 mA on the negative regulator. The positive source-driver power supply's regulation voltage (AVDD) is set by writing the avdd[5:0] value in the AVDD\_SET register using the I<sup>2</sup>C interface, and can be programmed into non-volatile memory. The default AVDD output voltage is 6.8V.

The negative source-driver supply voltage (NAVDD) is automatically tightly regulated to -AVDD within ±34mV. NAVDD cannot be adjusted independently of AVDD.

The AVDD boost converter is a current-mode converter with two internal switches and internal compensation. The direct output of the converter is HVINP while AVDD is a switched-output version. The NAVDD converter is a current-mode converter with one internal switch, an external diode and internal compensation.

#### **Gate-Driver Power Supplies**

The positive gate-driver power supply (VG<sub>ON</sub>) is a regulated charge-pump tripler and generates up to +20.2V. Note also that the maximum output voltage is 3 x AVDD -  $R_{ONTOTAL} \times I_{VGON} \times K$ , where  $R_{ONTOTAL}$  is typically 30 $\Omega$  and K is a factor 0.75. In cases where a doubler charge pump is sufficient, set the cp\_2stage bit and leave pins FC1- and FC1+ unconnected in order to increase efficiency.

The negative gate-driver power supply (VG<sub>OFF</sub>) generates a maximum negative voltage of -18.2V and requires external diodes and capacitors. The VG<sub>ON</sub> and VG<sub>OFF</sub> blocks switch at the same frequency as the AVDD and NAVDD converters.

Both supplies are capable of output currents up to 15mA, assuming sufficient headroom. The VG<sub>ON</sub> and VG<sub>OFF</sub> regulation voltages are set by writing the vgon[5:0] and vgoff[5:0] values in the register map using the  $I^2C$  interface, and can be stored in the non-volatile section of the register map.

#### Sequencing

The power-on and power-off sequences are controlled by the seq\_set[2:0] bits in the VCOM\_L register. The setting should be written before the sequence is to be executed and should not be changed during the turn-on or turn-off sequences. The sequence options are as follows:

	SEQL	JENCE SET	BITS	POWER-ON				POWE				
Sequence No.	seq_set2	seq_set1	seq_set0	1st	2nd after t1 ms	3rd after t2 ms	4th after t3 ms	1st	2nd after t3 ms	3rd after t2 ms	4th after t1 ms	NOTES
1	0	0	0	AVDD	NAVDD	VG <sub>OFF</sub>	VG <sub>ON</sub> / VCOM	VGON/ VCOM	VG <sub>OFF</sub>	NAVDD	AVDD	
2	0	0	1	AVDD	NAVDD	VG <sub>ON</sub>	VG <sub>OFF</sub> / VCOM	VG <sub>OFF</sub> / VCOM	VG <sub>ON</sub>	NAVDD	AVDD	
3	0	1	0	NAVDD	AVDD	VG <sub>OFF</sub>	VG <sub>ON</sub> / VCOM	VG <sub>ON</sub> / VCOM	VG <sub>OFF</sub>	AVDD	NAVDD	Default setting
4	0	1	1	NAVDD	AVDD	VGON	VG <sub>OFF</sub> / VCOM	VG <sub>OFF</sub> / VCOM	VG <sub>ON</sub>	AVDD	NAVDD	
5	1	0	0	NAVDD	VG <sub>OFF</sub>	AVDD	VG <sub>ON</sub> / VCOM	VGON/ VCOM	AVDD	VG <sub>OFF</sub>	NAVDD	
6	1	0	1	VG <sub>OFF</sub>	VG <sub>ON</sub>	NAVDD	AVDD/ VCOM	AVDD/ VCOM	NAVDD	VG <sub>ON</sub>	VG <sub>OFF</sub>	

### Table 2. Available Sequences

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

7	1	1	0	AVDD/ NAVDD	VG <sub>OFF</sub>	VG <sub>ON</sub> / VCOM	-	VG <sub>ON</sub> / VCOM	VG <sub>OFF</sub>	AVDD/ NAVDD	-	
8	1	1	1	AVDD/ NAVDD	VG <sub>ON</sub>	VG <sub>OFF</sub> / VCOM	-	VG <sub>OFF</sub> / VCOM	VGON	AVDD/ NAVDD	-	

#### Table 2. Available Sequences (continued)

The times in the above table are determined by the delayt1, delayt2 and delayt3 settings in the DELAY-VCOM\_LSB register. The fastest power-up is obtained by setting the delays to 0.

The output voltages are not monitored during off sequencing; each output is turned off in turn using the programmed delays. When the delays are set to zero, outputs are turned off in sequence with 1ms delays .A sequence can be stored in non-volatile memory by writing to the burn\_otp\_reg register.

The V18 linear regulator is powered down 200ms after the power-down sequence is complete. After this time, the device is in shut-down mode and can be restarted by setting the EN input high.

#### Sequencing Diagram



Figure 1. Sequencing Example (Sequence 1, Not to Scale)

#### VCOM Buffer

The VCOM output voltage is programmed using I<sup>2</sup>C to a value between -2.49V and +1V. The 9-bit value can also be stored in non-volatile memory. The most-significant bits of the VCOM voltage setting are in the VCOM25 register while the least-significant bit is the vcom25\_0 bit in the DELAY-DELAYVCOM\_LSB register.

The VCOM buffer can output peak currents up to  $\pm$ 120mA. If the VCOM output voltage deviates from the set value by more than 0.25V, a VCOM fault is detected and flagged with the vcom\_flt bit in the FAULT2 register. When this fault is detected, the VCOM buffer continues to function—it is not automatically disabled. Note that a fault condition can lead to high power dissipation in the VCOM buffer and could lead to thermal shutdown of the entire device. If the VCOM buffer is continuously in current limit for more than the time set by tfault[1:0], it is disabled together with the AVDD, NAVDD, VG<sub>H</sub> and VG<sub>L</sub> outputs to avoid damage to the IC. Also in this case the vcom\_flt bit is set.

The maximum capacitive load on the VCOM output is 10nF. If higher capacitance loads are used, a series resistor should be employed to maintain stability.

To calculate the value to write to the VCOM25 register use the following equation:

 $VCOM25 = \frac{V_{COM} + 2.49}{0.00683}$ 

The correspondence between the VCOM set value and the VCOM voltage is shown in table 2.

### Table 3. VCOM Settings

VCOM25 REGISTER VALUE	VCOM VOLTAGE (V)
0x1FF	1
0x1FE	0.9932
0x16E	+0.0098
0x16D	+0.003
0x16C	-0.0039
0x002	-2.4763
0x001	-2.4832
0x000	-2.49

#### VCOMN Negative Power Supply

A linear regulator is implemented to derive a regulated -3.5V for the VCOM buffer from the NAVDD supply. The npn transistor connected to the VCB pin acts as the pass transistor of the regulator. The peak output current of the regulator is the same as the peak negative drive current from the VCOM output, or at least 120mA. The device senses the voltage at VCOMN and regulates it to -3.5V by driving VCB. The peak drive current for the base of the external npn is at least 5mA.

#### Limiting the Range of VCOM Voltage

When temperature compensation is not enabled, it is possible to limit the excursion of VCOM to a range between the values set in the VCOM\_MIN and VCOM\_MAX registers. If an attempt is made to write a value outside the set range to VCOM25, the VCOM output voltage is not updated and the I<sup>2</sup>C interface issues a NACK.

#### VCOM Temperature Compensation

The VCOM output voltage can be compensated for temperature changes using a temperature-sensitive component (e.g. an NTC thermistor) connected to the TEMP input or an internal temperature sensor. Select the sensor to be used with the int\_sensor bit in the CONFIG register (the default configuration is to use the external sensor). The TEMP pin is forced to 625mV and the current drawn from it is mirrored on the R<sub>REF</sub> pin. The voltage generated due to the resistor on R<sub>REF</sub> is fed to the internal 8-bit ADC, which has a reference voltage of 1.25V. The input to the ADC is therefore as follows:

$$V_{\text{ADC}} = \frac{0.625 \times R_{\text{RREF}}}{R_{\text{TEMP}}}$$

With reference to Figure 2:  $R_{\text{TEMP}} = (R_{\text{NTC}} | | R1) + R2$ 

The highly non-linear NTC characteristic can be modified depending on which temperature (cold, room, or hot) necessitates the highest resolution. As an example in <u>Figure 2</u>, a reference resistor is connected to  $R_{REF}$  while a combination of the NTC and two low-TC resistors R1 and R2 are connected to TEMP. In this way, an ADC reading that is steeper at higher temperatures is obtained, enhancing the resolution of the ADC there. When temperature compensation is enabled, the value of the voltage on the  $R_{REF}$  pin is available in the TEMP (0x01) register.

Temperature compensation is enabled by setting the T\_comp\_en bit in the DELAY-VCOM\_LSB register. When T\_comp\_en is high, the voltage on the R<sub>REF</sub> pin is measured and the VCOM output voltage is updated at a rate of 1Hz. At start-up, even with temperature compensation enabled, there is a delay before compensation becomes active due to the time needed to sample the temperature. For this reason, the device always starts up with the VCOM25 voltage value on VCOM.

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The VCOM value at 25°C is the value written in the VCOM25 register together with the LSB from DELAY-VCOM\_LSB register. This value serves as the reference for all other VCOM values. The 5-bit values in the VCOM\_L, and VCOM\_H1 registers represent the change in VCOM from the VCOM25 value at the temperature represented by an ADC reading of VTEMP\_L and VTEMP\_H1. The value in the VCOM\_H2 register represents the positive shift in VCOM from VCOM\_H1. The VCOM\_L value represents a negative shift in VCOM while VCOM\_H1 and VCOM\_H2 represent positive shifts.

#### **NTC Connection Diagram**



Figure 2. Possible NTC Connection

#### Internal Temperature Sensor

The internal temperature sensor senses the junction temperature of the IC which may be significantly different from the ambient temperature. To use the internal sensor, set the int\_sensor bit in the CONFIG register to 1. The internal temperature sensor has a temperature coefficient of 2mV/°C and a nominal output voltage of 620mV at 25°C.

When the internal temperature sensor is selected, it is connected directly to the ADC input at RREF.

#### **Temperature Compensation Curve**



Figure 3. Temperature Compensation Curve

#### Fault Handling

The reaction to faults is dependent on whether the device is in  $I^2C$  or stand-alone mode.

In I<sup>2</sup>C mode, the following faults, if not masked, cause the FLTB pin to assert low: avdd\_uv, navdd\_uv, vgon\_uv, vgoff\_uv, vcom\_flt, nv\_flt, th\_shdn, vin\_uvlo, and par\_err. The th\_warn fault is masked by default and must be explicitly enabled using the th\_warn\_mask bit.

When the ADD pin is left floating (I<sup>2</sup>C interface not used) the FLTB pin outputs a pulse train of varying duty cycle depending on the detected fault as shown in <u>Table 4</u>.

### Table 4. FLTB Duty Cycle in Stand-Alone Mode

DUTY-CYCLE	FAULT				
75%	VG <sub>ON</sub> or VG <sub>OFF</sub> fault				
50%	AVDD, NAVDD or HVINP fault				
25%	VCOM fault				
0% (continuously low)	NV fault or thermal shutdown				

The frequency at the FLTB pin is 1kHz when indicating a fault. If multiple faults are present, the highest-priority fault is indicated. The list above is in order of priority with the highest priority listed last.

#### Undervoltage Faults on the Source, Gate and VCOM Outputs

When an undervoltage is detected on any of the AVDD, NAVDD,  $VG_{ON}$ , or  $VG_{OFF}$  outputs, all of the outputs are turned off and the appropriate fault bit is set in the FAULT1 register. At the same time, the FLTB pin asserts low. Depending on the setting of the tretry[1:0] bits, the subsequent behavior of the device is as follows:

tretry = 01, 10 or 11: After 0.95s or 1.9s a retry is performed where all outputs are turned on in the appropriate sequence. If the fault is still present, the output will be disabled again after tfault[1:0]. A total of three retries are performed, after which no further retry attempts are performed (the device can be restarted by toggling power or the EN pin or by using the RESTART command). If tretry = 11 retries continue until the fault is removed and normal

function can resume.

• tretry = 00: No retry is attempted (the device can be restarted by toggling power or the EN pin or by using the RESTART command).

If a short-circuit is encountered during start-up, device operation is halted, all outputs are disabled, and the subsequent behavior depends on the setting of retry[1:0] as described above. The short-circuit checks on  $VG_{ON}$  and  $VG_{OFF}$  are enabled 1ms after the pins are enabled.

During retry, faults are no longer monitored and the fault or faults which caused retry are indicated using the corresponding fault bits. During retry, the FLTB pin asserts low unless the fault which caused the retry is masked.

#### Thermal Warning and Shutdown

When the junction temperature reaches 125°C, the thermal warning bit is set. The device takes no further action.

If the device junction temperature reaches 160°C, all outputs are turned off immediately. When the junction temperature drops by 15°C, the outputs are re-enabled using the stored sequence.

#### **NV Memory**

The MAX25220/MAX25221/MAX25221B include five blocks of one-time-programmable memory. The user can store the block of volatile registers from 0x07 to 0x15 in non-volatile memory which is in turn mapped to register locations 0x17 to 0x25. Note that before the non-volatile memory has been programmed, a read from the locations 0x17 to 0x25 yields the result 0xFF.

The contents of the non-volatile memory are protected by a single-error correction/double-error detection (SECDED) redundant code while data transfer from non-volatile memory to registers 0x07 to 0x15 is protected by a parity check. If the parity check fails, a retry is performed two times. If all three attempts are unsuccessful, the device does not start up, the nv\_flt bit is set, and the FLTB pin is asserted low. If the SECDED check fails, the device does not start up, the nv\_flt bit is set, and the FLTB pin is asserted low.

If there are no errors, the outputs are turned on with the stored values and in the stored sequence.

To store the contents of registers 0x07 to 0x15 to non-volatile memory a voltage source of 8.5V  $\pm$ 2% capable of supplying more than 25mA should be connected to the V<sub>PROG</sub> pin. When the V<sub>PROG</sub> voltage is stable an I<sup>2</sup>C NV write command can be performed by writing to the burn\_otp\_reg register. If the NV write is unsuccessful (because the V<sub>PROG</sub> voltage was out of range or because of a general memory error) the nv\_flt bit is set, FLTB pin goes low. After an NV write command is executed, the nv\_flt bit should be checked. If nv\_flt is high another NV write can be attempted.

Connect V<sub>PROG</sub> to GND if non-volatile memory is not used.

Ensure that temperature compensation is disabled when programming VCOM.

#### Auto-Refresh Function

When the refresh bit in register CONFIG is set, the device reads from the non-volatile registers at intervals of 1s and writes the data into the corresponding volatile registers. This avoids the effect of possible corruption of the volatile registers. Auto-refresh reads are subject to error correction in the same way as the initial read after device power-up.

When programming the non-volatile memory, the auto-refresh function should be enabled immediately before performing the burn\_otp\_reg write. See the section *Using the NV Memory* in <u>Applications Information</u>.

#### **BURN, REBOOT and RESTART Commands**

The BURN and REBOOT commands are used to store the contents of registers 0x07 to 0x15 in non-volatile memory or to fetch the contents of non-volatile memory and load them into registers 0x07 to 0x15, respectively. The RESTART command is used to restart the device from a latched-fault mode. When a RESTART command is performed, all fault bits are cleared.

A BURN command is performed by writing to register address 0x78 (burn\_otp\_reg).

- A REBOOT command is performed by writing to register address 0x79 (reboot\_otp\_reg).
- A RESTART command is performed by writing to register address 0x7A (soft\_restart).

When parity checking is enabled and one of these user commands is sent to the device, the third byte should be such as to have even parity over the 3 bytes sent.

### I<sup>2</sup>C Interface

The MAX25220/MAX25221/MAX25221B include an I<sup>2</sup>C, 2-wire serial interface consisting of a serial-data line (SDA) and a serial-clock line (SCL). SDA and SCL facilitate communication between the IC and the master at clock rates up to 400kHz. The master, typically a microcontroller, generates SCL and initiates data transfer on the bus.

The Slave ID of the MAX25220/MAX25221/MAX25221B depends on the connection of the ADD pin according to Table 4.

A master device communicates with the MAX25220/MAX25221/MAX25221B by transmitting the correct Slave ID with appended R/W bit, followed by the register address and data word (for a write transaction only). Each transmit sequence is framed by a START (S) or Repeated START (Sr) condition, and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge clock pulse.

The IC's SDA line operates as both an input and an open-drain output. A pullup resistor greater than  $1k\Omega$  is required on the SDA bus. In general, the resistor should be selected as a function of bus capacitance such that the rise time on the bus is not greater than 120ns. The IC's SCL line operates as an input only. A pullup resistor greater than  $1k\Omega$  is required on SCL if there are multiple masters on the bus, or if the master in a single-master system has an open-drain SCL output. In general, for the SCL-line resistor selection, the same recommendations as for SDA apply. Series resistors in line with SDA and SCL are optional. The SCL and SDA inputs suppress noise spikes to assure proper device operation even on a noisy bus.

#### I<sup>2</sup>C Slave Addresses

### Table 5. I<sup>2</sup>C Slave Addresses

			DEVIC	CE ADD	WRITE	READ				
ADD FIN CONNECTION	A6	A5	A4	A3	A2	A1	A0	ADDRESS	ADDRESS	
GND	0	1	0	0	0	0	1	0x42	0x43	
V18	0	1	0	1	0	0	1	0x52*	0x53	

\* On the MAX25221B writing to the device is not possible when ADD is connected to V18.

#### Parity Checking

Even parity checking for write transactions can be enabled by setting the par\_en bit in REG\_CTRL to 1. The parity bit is the most-significant bit of the register address byte and should be set to attain even parity. The parity check is performed over all 3 bytes received by the device: the slave address, the register address, and the data payload. Burst-mode write is not supported when parity checking is enabled; a complete I<sup>2</sup>C transaction is needed to write to each single register. When a parity bit error is detected the par err bit is set, the I<sup>2</sup>C interface issues a NACK and no write is performed.

When writing any of the BURN, REBOOT, and RESTART commands, parity must be adjusted by changing the third or payload byte; the command byte must not be changed.

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Register Map**

#### MAX25220/MAX25221/MAX25221B

ADDRESS	NAME	MSB							LSB
USER REG	ISTERS		1	l	1	1	1		1
0x00	DEVICE[7:0]	-	-			dev_i	d[5:0]		
0x01	TEMP[7:0]		1		temp	p[7:0]			
0x02	REG_CTRL[7:0]	par_en	start	_	_	_		rev_id[2:0]	
0x03	FLTMASK1[7:0]	-	avdd_uv _mask	-	navdd_u v_mask	_	vgon_uv _mask	-	vgoff_uv _mask
0x04	FLTMASK2[7:0]	-	par_err_ mask	vin_uvlo _mask	hvinp_uv _mask	-	-	vcom_flt _mask	th_warn_ mask
0x05	FAULT1[7:0]	-	avdd_uv	-	navdd_u v	-	vgon_uv	-	vgoff_uv
0x06	FAULT2[7:0]	v18oor	par_err	vin_uvlo	hvinp_uv	th_shdn	nv_flt	vcom_flt	th_warn
0x07	CONFIG[7:0]	int_sens or	refresh	en_ss	fSW	tretry	/[1:0]	tfaul	t[1:0]
0x08	DELAY- VCOM_LSB[7:0]	delay	t1[1:0]	delay	t2[1:0]	delay	t3[1:0]	T_comp_ en	vcom25_ 0
0x09	VCOM25[7:0]				vcom2	25[7:0]			
0x0A	VCOM_L[7:0]		seq_set[2:0]	]			vcom_l[4:0]		
0x0B	VCOM_H1[7:0]	-	-	-		١	/com_h1[4:(	)]	
0x0C	VCOM_H2[7:0]	-	-	-		١	/com_h2[4:(	)]	
0x0D	VTEMP25[7:0]				vtemp	25[7:0]			
0x0E	VTEMP_L[7:0]				vtemp	_I[7:0]			
0x0F	VTEMP_H1[7:0]				vtemp_	_h1[7:0]			
0x10	VTEMP_H2[7:0]				vtemp_	_h2[7:0]			
0x11	VCOM_MIN[7:0]				vcom_r	min[7:0]			
0x12	VCOM_MAX[7:0]				vcom_r	nax[7:0]			
0x13	AVDD_SET[7:0]	-	_			avdo	l[5:0]		
0x14	<u>VGON[7:0]</u>	-	cp_2stag e			vgor	n[5:0]		
0x15	<u>VGOFF[7:0]</u>	-	-			vgof	f[5:0]		
0x17	NV_CONFIG[7:0]	nv_int_s ensor	nv_refres h	nv_en_s s	nv_fSW	nv_rei	try[1:0]	nv_tfa	ult[1:0]
0x18	NV_DELAY- VCOM_LSB[7:0]	nv_dela	ayt1[1:0]	nv_dela	ayt2[1:0]	nv_dela	ayt3[1:0]	nv_T_co mp_en	nv_vcom 25_0
0x19	NV_VCOM25[7:0]				nv_vcor	m25[7:0]			
0x1A	NV_VCOM_L[7:0]	nv	/_seq_set[2	:0]		n	v_vcom_l[4:	0]	
0x1B	NV_VCOM_H1[7:0]	-	_	_		nv	_vcom_h1[4	1:0]	
0x1C	NV_VCOM_H2[7:0]	-	-	-		nv	_vcom_h2[4	1:0]	
0x1D	NV_VTEMP25[7:0]				nv_vterr	p25[7:0]			
0x1E	NV_VTEMP_L[7:0]				nv_vten	np_l[7:0]			
0x1F	NV_TEMP_H1[7:0]				nv_vtem	p_h1[7:0]			

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

ADDRESS	NAME	MSB							LSB	
0x20	NV_TEMP_H2[7:0]		nv_vtemp_h2[7:0]							
0x21	NV_VCOM_MIN[7:0]				nv_vcom	_min[7:0]				
0x22	NV_VCOM_MAX[7:0]				nv_vcom	_max[7:0]				
0x23	NV_AVDD_SET[7:0]	-	-			nv_av	dd[5:0]			
0x24	<u>NV_VGON[7:0]</u>	-	nv_cp_2 stage			nv_vg	on[5:0]			
0x25	NV_VGOFF[7:0]	-	-			nv_vg	off[5:0]			
USER COM	MANDS									
0x78	burn_otp_reg[7:0]				burn_c	otp[7:0]				
0x79	reboot_otp_reg[7:0]	reboot_otp[7:0]								
0x7A	soft_restart[7:0]				soft_res	start[7:0]				

### **Register Details**

#### **DEVICE (0x00)**

BIT	7	6	5	4	3	2	1	0			
Field	-	-	dev_id[5:0]								
Reset	-	-									
Access Type	_	_	Read Only								
BITFIE	LD	BITS	DESCRIPTION								
dev_id		5:0	Device ID. Reads 0x20/21								

#### TEMP (0x01)

BIT	7	6	5	4	3	2	1	0		
Field		temp[7:0]								
Reset		0x0								
Access Type	Read Only									
BITFIEI	LD	BITS		DESCRIPTION						
temp		7:0 Voltage reading from R <sub>REF</sub> pin.								

#### REG\_CTRL (0x02)

BIT	7	6	5	4	3	2 1 0		
Field	par_en	start	-	-	-	rev_id[2:0]		
Reset	0x0	0x0	-	-	-	0x1		
Access Type	Write, Rea	d Write, Read	_	_	_	Read Only		
BITFIEI	LD	BITS		DESCRIPTION				
par_en		7	P tc	arity enable bit. W the device.	hen 1 this bit e	nables parity checking on write transaction		

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION
start	6	Enable bit. When this bit is set to 1 the turn-on sequence set using the seq_set bits is executed. The default value of this bit is 0 except in the MAX25221B where it is 1.
rev_id	2:0	Revision ID. Reads 0x1.

#### FLTMASK1 (0x03)

BIT	7	6	5		4	3	2	1	0	
Field	_	avdd_uv_m ask	_		navdd_uv_ mask	_	vgon_uv_m ask	-	vgoff_uv_m ask	
Reset	_	0x0	_		0x0	-	0x0	-	0x0	
Access Type	_	– Write, Read –			Write, Read	_	Write, Read	-	Write, Read	
BITFIELD BITS						DE	SCRIPTION			
avdd_uv_mask	(	6		When 1 this bit prevents an undervoltage on AVDD from asserting FLTB low.						
navdd_uv_mas	sk	4		When 1 this bit prevents an undervoltage on NAVDD from asserting FLTB low.						
vgon_uv_mask 2			When 1 this bit prevents an undervoltage on VGON from asserting FLTB low.							
vgoff_uv_mask		0		Wher low.	When 1 this bit prevents an undervoltage on VGOFF from asserting FLTB low.					

#### FLTMASK2 (0x04)

BIT	7	6	5	;	4	3	2	1	0
Field	-	par_err_ma sk	vin_uv as	/lo_m ⊧k	hvinp_uv_m ask	-	-	vcom_flt_m ask	th_warn_ma sk
Reset	-	0x0	0x	:0	0x0	-	-	0x0	0x1
Access Type	cess _ pe _		Write,	Read	Write, Read	-	-	Write, Read	Write, Read
BITFIELD BITS				DESCRIPTION					
par_err_mask		6		Wher	n 1 prevents pa	rity errors from	asserting the l	FLTB pin.	
vin_uvlo_mask		5		Wher	1 this bit preve	ents an underv	oltage on IN fro	om asserting th	e FLTB pin.
hvinp_uv_mas	k	4		Mask bit for hvinp_uv diagnostic. When 1 an undervoltage on HVINP does cause FLTB to assert.					/INP does not
vcom_flt_mask 1			When 1 this bit prevents a fault on VCOM from asserting FLTB low.						
th_warn_mask		0		Wher low.	When 1 this bit prevents an overtemperature warning from asserting FLTB low.				

#### FAULT1 (0x05)

BIT	7	6	5		4	3	2	1	0
Field	-	avdd_uv	-		navdd_uv	-	vgon_uv	-	vgoff_uv
Reset	-	0x0	_		0x0	-	0x0	_	0x0
Access Type	_	Read Clears All	_		Read Clears All	-	Read Clears All	-	Read Clears All
BITFIEI	LD	BITS		DESCRIPTION					
avdd_uv		6		Wher	1 this bit indic	ates an under	oltage on AVD	D.	

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION
navdd_uv	4	When 1 this bit indicates an undervoltage on NAVDD.
vgon_uv	2	When 1 this bit indicates an undervoltage on VG <sub>ON</sub> .
vgoff_uv	0	When 1 this bit indicates an undervoltage on VG <sub>OFF</sub> .

#### FAULT2 (0x06)

BIT	7	6	5	4 3 2 1 O					
Field	v18oor	par_err	vin_u	uvlo hvinp_uv th_shdn nv_flt vcom_flt th_				th_warn	
Reset	0x0	0x0	0x	)x0 0x0 0x0 0x0 0x0				0x0	
Access Type	Read Clears A	Read II Clears All	Rea Clear	ad 's All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All
BITFIE	LD	BITS			DE	SCRIPTION			
v18oor		7		Indica level	ates that the 1.8 or below its une	8V output is ou dervoltage leve	t of range, eithe l.	er above its ov	ervoltage
par_err		6		Indicates that a parity error was detected on an I <sup>2</sup> C transaction.					
vin_uvlo		5		Indicates an undervoltage condition on the IN pin. When this happens the device turns off all outputs and waits for IN to return above the IN UVLO level after which the outputs are re-enabled in the programmed sequence.					ppens the I UVLO level, nce.
hvinp_uv		4		Wher	n 1 this bit indic	ates an underv	oltage on the b	boost output, H	VINP.
th_shdn		3		Wher	n 1 this bit indic	ates an overte	mperature shut	down.	
nv_flt		2		Non-v mem	volatile memory ory to working r	y failure - unsuo memory or mor	ccessful transfe e than one erro	er of the conten or detected.	ts of NV
vcom_flt		1		When 1 indicates a fault on the VCOM output either due to it being 0.25V away from its set value (unfiltered) or because the VCOM buffer was in current limit for a time $t_{fault}$ .					
th_warn		0		Wher	n 1 this bit indic	ates a thermal	warning.		

#### CONFIG (0x07)

BIT	7	6	5	4		3	2	1	0	
Field	int_sensor	refresh	en_ss	fSW		tretry[1:0]		tfault	[1:0]	
Reset	0x0	0x0	0x0	0x0		0>	(1	0×	( <b>0</b>	
Access Type	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read Write, Read Wr					
BITFIELD	BITS		DESCRIPT	ION			D	ECODE		
int_sensor	7	Set this bit to temperature	o 1 to use the in sensor.	nternal						
refresh	6	When this bi registers are volatile regis	t is 1 the conte automatically sters every seco	nts of the NV copied to the ond.		0x0: Ref 0x1: Ref	resh disabled. resh enabled.			
en_ss	5	Enable sprea	ad-spectrum by	y setting this bit	t to					
fSW	4	Sets switchin	ng frequency.			0x0: 2.1MHz 0x1: 420kHz				
tretry	3:2	Sets retry tir	ne after a fault.			0x0: Retry disabled 0x1: Retry after 0.95s, total 3 retries. 0x2: Retry after 1.9s, total 3 retries. 0x3: Retry after 1.9s				

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE
tfault	1:0	Sets fault delay time.	0x0: 15ms 0x1: 30ms 0x2: 60ms 0x3: 90ms

#### DELAY-VCOM\_LSB (0x08)

BIT	7	6	5	4	3	2	1	0		
Field	dela	delayt1[1:0]		t2[1:0]	delayt3[1:0]		T_comp_en	vcom25_0		
Reset		0x2	0	x2	0)	k2	0x0	0x0		
Access Type	Write, Read		Write	, Read	Write, Read		Write, Read	Write, Read		
BITFIEI	D	BITS		DESCRIPTION						
delayt1		7:6	7:6 Set delay t1 in the start-up sequence. Choose between 15ms.							
delayt2		5:4	Set of 15ms	lelay t2 in the s s.	art-up sequend	ce. Choose bet	ween 0, 5ms, 1	I0ms and		
delayt3		3:2	Set of 15ms	Set delay t3 in the start-up sequence. Choose between 0, 5ms, 10ms 15ms.						
T_comp_en		1	When ampl	When 1 this bit enables temperature compensation of the output of the amplifier.						
vcom25_0		0	LSB	of VCOM settin	g at 25°C.					

#### VCOM25 (0x09)

BIT	7	6	5	4	3	2	1	0		
Field		vcom25[7:0]								
Reset		0x0								
Access Type		Write, Read								
BITFIEI	LD	BITS	BITS DESCRIPTION							
vcom25		7:0	VCO	VCOM setting at 25°C.						

#### VCOM\_L (0x0A)

BIT	7	6	5	4	3	2	1	0					
Field		seq_set[2:0]				vcom_l[4:0]							
Reset		0x2				0x00							
Access Type		Write, Read		Write, Read					Write, Read				
BITFIELD	BITS		DESCRIPT	TION DECODE									
seq_set	7:5	Sequence s	election bits.		0x0: Sec 0x1: Sec 0x2: Sec 0x3: Sec 0x4: Sec 0x5: Sec 0x6: Sec 0x7: Sec	quence 1. quence 2. quence 3. quence 4. quence 5. quence 6. quence 7. quence 8.							

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE
vcom_l	4:0	Delta VCOM at at the temperature corresponding to VTEMP_L. This value sets the difference between the VCOM value at 25°C and that at VTEMP_L.	

#### VCOM\_H1 (0x0B)

BIT	7	6	5		4	3	2	1	0		
Field	-	-	-		vcom_h1[4:0]						
Reset	-	-	-			0x00					
Access Type	_	-	-		Write, Read						
BITFIE	LD	BITS			DESCRIPTION						
vcom_h1		4:0		Delta VCON	elta VCOM at VTEMP_H1. This value sets the difference betwee COM value at 25°C and that at VTEMP H1.				een the		

#### VCOM\_H2 (0x0C)

BIT	7	6	5		4	3	2	1	0		
Field	-	-	-				vcom_h2[4:0]				
Reset	-	-	-			vcom_h2[4:0] 0x0 Write, Read DESCRIPTION					
Access Type	_	-	-			Write, Read					
BITFIE	LD	BITS			DESCRIPTION						
vcom_h2		4:0		Delta VCO	VCOM at VTE M value at VTE	Write, Read DESCRIPTION COM at VTEMP_H2. This value sets the difference between the value at VTEMP_H1 and that at VTEMP_H2.					

#### VTEMP25 (0x0D)

BIT	7	6	5	4	3	2	1	0			
Field				vtemp25[7:0]							
Reset		0x0									
Access Type		Write, Read									
BITFIEI	LD	BITS		DESCRIPTION							
vtemp25	7:0			Voltage at TEMP pin at 25°C.							

#### VTEMP\_L (0x0E)

BIT	7	6	5	4	3	2	1	0		
Field				vtemp	_I[7:0]					
Reset		0x0								
Access Type		Write, Read								
BITFIEI	D	BITS			DE	SCRIPTION				
vtemp_l		7:0	Volta com	ige at TEMP pir pensation curve	n correspondin	g to low-tempe	rature breakpoi	int in VCOM		

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

#### VTEMP\_H1 (0x0F)

BIT	7	6	5	4	3	2	1	0	
Field				vtemp_	_h1[7:0]				
Reset				0:	k0				
Access Type		Write, Read							
BITFIE	LD	BITS			DE	SCRIPTION			
vtemp_h1		7:0	Volta VCO	ge at TEMP pir M compensatio	n correspondir n curve.	ng to first high-te	emperature bre	akpoint in	

#### **VTEMP H2 (0x10)**

BIT	7	6	5	4	3	2	1	0	
Field				vtemp_	h2[7:0]				
Reset		0x0							
Access Type	Write, Read								
BITFIEI	D	BITS DESCRIPTION							
vtemp_h2	/temp_h2 7:0			Voltage at TEMP pin corresponding to second high-temperature breakpoint in VCOM compensation curve.					

#### VCOM\_MIN (0x11)

BIT	7	6	5	4	3	2	1	0			
Field				vcom_min[7:0]							
Reset		0x0									
Access Type		Write, Read									
BITFIEI	D	BITS		DESCRIPTION							
vcom_min		7:0	Lowe	Lower limit for VCOM setting.							

#### VCOM\_MAX (0x12)

BIT	7	6	5	4	3	2	1	0			
Field				vcom_max[7:0]							
Reset		0xFF									
Access Type		Write, Read									
BITFIEI	D	BITS		DESCRIPTION							
vcom_max		7:0	Uppe	Upper limit for VCOM setting.							

#### AVDD\_SET (0x13)

BIT	7	6	5	4	3	2	1	0		
Field	-	-		avdd[5:0]						
Reset	-	-		0x1A						
Access Type	-	_		avdd[5:0] 0x1A Write, Read						

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE
			0x0: 4.2
			0x1: 4.3
			0x2: 4.4
			0x3: 4.5
			0x4: 4.6
			0x5: 4.7
			UX0: 4.8
			0x7.4.9
			0x0: 5 0x9: 5 1
			0xA: 5.2
			0xB: 5.3
			0xC: 5.4
			0xD: 5.5
			0xE: 5.6
			0xF: 5.7
			0x10: 5.8
			0x11: 5.9
			0x12:6
			UX13: 6.1
			0x14. 0.2 0x15: 6.3
		0x16: 6.4	0x16: 6.4
			0x17:65
			0x18: 6.6
			0x19: 6.7
			0x1A: 6.8
			0x1B: 6.9
avdd	5:0	Sets AVDD and NAVDD voltages.	0x1C: 7V
			0x1D: 7.1
			0x1E: 7.2
			UX1F: 7.3 0v20: 7.4
			UX2U: 7.4
			0x21.7.5
			0x23: 7.7
			0x24: 7.8
			0x25: 7.9
			0x26: 8
			0x27: 8.1
			0x28: 8.2
			0x29: 8.3
			0x2A: 8.4
			0x2D. 0.3
			0x20: 8.0
			0x2E: 8.8
			0x2F: 8.9
			0x30: 9
			0x31: 9.1
			0x32: 9.2
			0x33: 9.3
			0x34: 9.4
			UX35: 9.5
		0x36: 9.6	UX30. 9.0 0v37: 0.7
			0x38: 9 8

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE
			0x39: 9.9
			0x3A: 10
			0x3B: 10.1
			0x3C: 10.2
			0x3D: 10.3
			0x3E: 10.4
			0x3F: 10.5

#### VGON (0x14)

BIT	7	6	5	4	3	2	1	0	
Field	-	cp_2stage	vgon[5:0]						
Reset	-	0x0			0>	(16			
Access Type	_	Write, Read			Write	, Read			
BITFIELD	BITS		DESCRIPT	ION		I	DECODE		
cp_2stage	6	Set this bit to charge-pum	o 1 when using p.	1 when using a two-stage					

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE
			0x0: 7.6
			0x1: 7.8
			0x2: 8
			0x3: 8.2
			0x4: 8.4
			UX5: 8.6
			0x0. 8.8
			0x7.9 0x8:0.2
			0x9: 9.4
			0xA: 9.6
			0xB: 9.8
			0xC: 10
			0xD: 10.2
			0xE: 10.4
			0xF: 10.6
			0x10: 10.8
			0x11: 11
			0x12: 11.2
			UX13: 11.4
			0x14. 11.0 0x15: 11.8
			0x16: 12
			0x17: 12 2
			0x18: 12.4
			0x19: 12.6
			0x1A: 12.8
			0x1B: 13
vgon	5:0	Sets VG <sub>ON</sub> voltage.	0x1C: 13.2
			0x1D: 13.4
			0x1E: 13.6
			UX1F: 13.8 0x20: 14
			0x20. 14 0x21: 14 2
			0x21.14.2 0x22.14.4
			0x23: 14.6
			0x24: 14.8
			0x25: 15
			0x26: 15.2
			0x27: 15.4
			0x28: 15.6
			0x29: 15.8
			0x2A: 16
			UX2B: 16.2
			0x20, 10,4 0x2D: 16,6
			0x2E: 16.8
			0x2E: 17
			0x30: 17.2
			0x31: 17.4
			0x32: 17.6
			0x33: 17.8
			0x34: 18
			0x35: 18.2
			0x36: 18.4
			UX37: 18.6
			UX38: 18.8

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE
			0x39: 19
			0x3A: 19.2
			0x3B: 19.4
			0x3C: 19.6
			0x3D: 19.8
			0x3E: 20
			0x3F: 20.2

#### VGOFF (0x15)

BIT	7	6	5	4	3	2	1	0		
Field	-	-		vgoff[5:0]						
Reset	-	-			0x	16				
Access Type	-	_			Write,	Read				

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE	
			0x0: -5.6	
			0x1: -5.8	
			0x2: -6	
				0x3: -6.2
			0x4: -6.4	
			UX5: -0.0	
			0x00.0 0x7: _7	
			0x8: -7 2	
			0x9: -7.4	
			0xA: -7.6	
			0xB: -7.8	
			0xC: -8	
			0xD: -8.2	
			0xE: -8.4	
			0xF: -8.6	
			0x10: -8.8	
			0x11:-9	
			0x12: -9.2 0x12: 0.4	
			0x139.4	
			0x15: -9.8	
		0x16: -10	0x16: -10	
			0x17: -10.2	
			0x18: -10.4	
			0x19: -10.6	
		0x1A: -10.8	0x1A: -10.8	
			0x1B: -11	
vgott	5:0	Sets VG <sub>OFF</sub> voltage.	0x1C: -11.2	
			0x1D11.4 0x1E: 11.6	
			0x1E: -11.8	
			0x20: -12	
			0x21: -12.2	
			0x22: -12.4	
			0x23: -12.6	
			0x24: -12.8	
			0x25: -13	
			UX26: -13.2	
			0x2713.4 0x28: 13.6	
			0x20: -13.0	
			0x2A: -14	
			0x2B: -14.2	
			0x2C: -14.4	
			0x2D: -14.6	
			0x2E: -14.8	
			0x2F: -15	
			0x30: -15.2	
			UX31:-15.4	
			UX3213.0 0x33: -15.8	
			0x34: -16	
			0x35: -16.2	
			0x36: -16.4	
		0x3010.4	0x37: -16.6	
			0x38: -16.8	

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION	DECODE
			0x39: -17
			0x3A: -17.2
			0x3B: -17.4
			0x3C: -17.6
			0x3D: -17.8
			0x3E: -18
			0x3F: -18.2

#### NV\_CONFIG (0x17)

Non-volatile configuration register

BIT	7	6	5	4	3	2	1	0		
Field	nv_int_sens or	nv_refresh	nv_en_ss	nv_fSW	nv_re	nv_retry[1:0] nv_tfault[1:				
Reset										
Access Type	Read Only	Read Only	Read Only	Read Only	Read	I Only	Read	l Only		
BITFIELD	BITS		DESCRIPT	ION		DECODE				
nv_int_senso r	7	When this bi sensor is us	When this bit is 1 the internal temperature sensor is used.							
nv_refresh	6	When this birregisters are volatile regis	it is 1 the conte automatically sters every sec	ents of the NV copied to the ond.						
nv_en_ss	5	When this bi enabled.	it is 1 spread-s	pectrum is						
nv_fSW	4	Sets switchi	Sets switching frequency.			MHz DkHz				
nv_retry	3:2	Sets retry tir	Sets retry time after a fault.							
nv_tfault	1:0	Sets retry tir	ne after a fault.							

#### NV\_DELAY-VCOM\_LSB (0x18)

BIT	7	6	5	4	3	2	1	0	
Field	nv_delayt1[1:0]		nv_dela	nv_delayt2[1:0]		nv_delayt3[1:0]		nv_vcom25 _0	
Reset							0x0		
Access Type	Read Only		Read	l Only	Read Only		Read Only	Read Only	
BITFIEI	LD	BITS			DE	SCRIPTION			
nv_delayt1		7:6	Set d 15ms	Set delay t1 in the start-up sequence. Choose between 0, 5ms, 10ms and 15ms.					
nv_delayt2		5:4	Set d 15ms	Set delay t2 in the start-up sequence. Choose between 0, 5ms, 10ms and 15ms.					
nv_delayt3		3:2	Set d 15ms	elay t3 in the s	tart-up sequen	ce. Choose bet	ween 0, 5ms, 1	I0ms and	
nv_T_comp_er	ı	1	When ampl	When 1 this bit enables temperature compensation of output of the VC amplifier.			he VCOM		
nv_vcom25_0 0 When 1 this bit enables temperat amplifier.			oles temperatur	e compensatio	n of output of t	he VCOM			

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

#### NV\_VCOM25 (0x19)

BIT	7	6	5	4	3	2	1	0		
Field	nv_vcom25[7:0]									
Reset										
Access Type	Read Only									
BITFIE	LD	BITS		DESCRIPTION						
nv_vcom25		7:0	VCO	VCOM setting at 25°C.						

#### NV\_VCOM\_L (0x1A)

BIT	7	6	5	4	3	2	1	0
Field		nv_seq_set[2:0	]	nv_vcom_l[4:0]				
Reset								
Access Type		Read Only Read Only						
BITFIEI	LD	BITS			DE	SCRIPTION		
nv_seq_set		7:5	Seq	Sequence selection bits.				
nv_vcom_l		4:0	Delt	elta VCOM at at the temperature corresponding to VTEMP_L. This value ts the difference between the VCOM value at 25°C and that at VTEMP_L.				This value VTEMP_L.

#### NV\_VCOM\_H1 (0x1B)

BIT	7	6	5		4	3	2	1	0
Field	-	-	-	- nv_vcom_h1[4:0]					
Reset	-	-	-	-					
Access Type	_	-	-		Read Only				
BITFIEI	LD	BITS		DESCRIPTION					
nv_vcom_h1		4:0		Delta VCOM at VTEMP_H1. This value sets the difference betw VCOM value at 25°C and that at VTEMP H1.			een the		

#### NV\_VCOM\_H2 (0x1C)

BIT	7	6	5	4	3	2	1	0
Field	-	-	_	nv_vcom_h2[4:0]				
Reset	-	-	-	-				
Access Type	_	_	_	Read Only				
BITFIEI	LD	BITS		DESCRIPTION				
nv_vcom_h2		4:0	Del VC0	Delta VCOM at VTEMP_H2. This value sets the difference between the VCOM value at VTEMP_H1 and that at VTEMP_H2.				een the

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

#### NV\_VTEMP25 (0x1D)

BIT	7	6	5	4	3	2	1	0
Field		nv_vtemp25[7:0]						
Reset								
Access Type	Read Only							
BITFIE	LD	BITS DESCRIPTION						
nv_vtemp25		7:0	Volta	Voltage at TEMP pin at 25°C.				

#### NV\_VTEMP\_L (0x1E)

BIT	7	6	5	4	3	2	1	0	
Field		nv_vtemp_I[7:0]							
Reset									
Access Type	Read Only								
BITFIE	LD	D BITS DESCRIPTION							
nv_vtemp_l		7:0 Voltage at TEMP pin corresponding to low-temperature breakpoint in VCOM compensation curve.							

#### NV\_TEMP\_H1 (0x1F)

BIT	7	6	5	4	3	2	1	0
Field				nv_vtem	p_h1[7:0]			
Reset								
Access Type		Read Only						
BITFIEI	LD	BITS DESCRIPTION						
nv_vtemp_h1	7:0 Voltage at TEMP pin corresponding to first high-temperature breakpoint in VCOM compensation curve.							

#### <u>NV\_TEMP\_H2 (0x20)</u>

BIT	7	6	5	4	3	2	1	0	
Field		nv_vtemp_h2[7:0]							
Reset									
Access Type		Read Only							
BITFIEI	LD	BITS DESCRIPTION							
nv_vtemp_h2		7:0 Voltage at TEMP pin corresponding to second high-temperature breakpoint in VCOM compensation curve.							

## Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

#### NV\_VCOM\_MIN (0x21)

BIT	7	6	5	4	3	2	1	0
Field		nv_vcom_min[7:0]						
Reset								
Access Type	Read Only							
BITFIE	LD	BITS DESCRIPTION						
nv_vcom_min		7:0 Lower limit for VCOM setting.						

#### NV\_VCOM\_MAX (0x22)

BIT	7	6	5	4	3	2	1	0
Field		nv_vcom_max[7:0]						
Reset								
Access Type		Read Only						
BITFIE	LD	BITS DESCRIPTION						
nv_vcom_max	7:0 Upper limit for VCOM setting.							

#### NV\_AVDD\_SET (0x23)

BIT	7	6	5	4	3	2	1	0
Field	-	-	nv_avdd[5:0]					
Reset	-	-						
Access Type	_	-	Read Only					
BITFIE	LD	BITS	DESCRIPTION					
nv_avdd		5:0	Sets AVDD and NAVDD voltages. See table for register 0x13.					

#### NV VGON (0x24)

BIT	7	6	5	4	3	2	1	0
Field	Ι	nv_cp_2sta ge	nv_vgon[5:0]					
Reset	-							
Access Type	-	Read Only	Read Only Read Only		I Only			
BITFIEI	D	D BITS		DESCRIPTION				
nv_cp_2stage		6	When this bit is set to 1 a two-stage charge-pump is used.					
nv_vgon		5:0	Sets VG <sub>ON</sub> voltage. See table for register 0x14.					

#### NV\_VGOFF (0x25)

BIT	7	6	5	4	3	2	1	0	
Field	-	-		nv_vgoff[5:0]					
Reset	-	-							
Access Type	-	-	Read Only						

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

BITFIELD	BITS	DESCRIPTION
nv_vgoff	5:0	Sets VGOFF voltage. See table for register 0x15.

#### burn\_otp\_reg (0x78)

BIT	7	6	5	4	3	2	1	0
Field	burn_otp[7:0]							
Reset		0x0						
Access Type	Write Only							
BITFIEI	ELD BITS DESCRIPTION							
burn_otp		7:0	Com regis	Command to copy the contents of registers 0x07-0x15 to the non-volatile registers 0x17-0x25.				ו-volatile

#### reboot\_otp\_reg (0x79)

BIT	7	6	5	4	3	2	1	0
Field	reboot_otp[7:0]							
Reset								
Access Type	Write Only							
BITFIEI	LD	BITS		DESCRIPTION				
reboot_otp		7:0	Com work	Command to copy the contents of the non-volatile registers 0x17-0x15 to the working registers 0x17-0x25.				2-0x15 to the

#### soft\_restart (0x7A)

BIT	7	6	5	4	3	2	1	0
Field	soft_restart[7:0]							
Reset		0x00						
Access Type	Write Only							
BITFIEI	LD	BITS		DESCRIPTION				
soft_restart		7:0	Com clear	Command used to re-start the device from a latched fault mode. All faults ar cleared when this command is executed.				All faults are

### **Applications Information**

#### **Boost Converter**

#### **Boost Converter Inductor Selection**

Three key inductor parameters must be specified for operation with the device: Inductance value (L), inductor saturation current ( $I_{SAT}$ ), and DC resistance ( $R_{DC}$ ). To determine the inductance value, first select the ratio of inductor peak-to-peak ripple current to average output current (LIR). Higher LIR values mean higher RMS inductor current and therefore higher I<sup>2</sup>R losses. To achieve a lower LIR value, a high-valued inductor, which may be physically larger, must be used. A good compromise between size and loss is to select a 30% to 60% peak-to-peak ripple current to average-current ratio (LIR from 0.3 to 0.6). If extremely thin high-resistance inductors are used, as is common for LCD-panel applications, the best LIR may lie between 0.5 and 1.0. The value of the inductor is determined below.

$$L = \frac{V_{\rm IN} \times D}{{\rm LIR} \times I_{\rm IN} \times f_{\rm SW}}$$

using:

$$I_{\rm IN} = \frac{V_{\rm OUT} \times I_{\rm OUT}}{\eta \times V_{\rm IN}}$$

$$D = 1 - \frac{V_{\rm IN}}{V_{\rm OUT}}$$

where  $V_{IN}$  is the input voltage,  $V_{OUT}$  is the output voltage,  $I_{OUT}$  is the output current,  $I_{IN}$  is the calculated average boost input current,  $\eta$  is the efficiency of the boost converter, D is the duty cycle, and  $f_{SW}$  is either 420kHz or 2.1MHz (the selected switching frequency of the boost converter). The efficiency of the boost converter can be estimated from the *Typical Operating Characteristics* and accounts for losses in the internal switch, inductor, and capacitors.

The inductor's saturation rating must exceed the maximum current-limit of 2.3A.

#### **Boost Output Filter Capacitor Selection**

The primary criterion for selecting the output filter capacitor is low effective series resistance (ESR). The product of the peak inductor current and the output filter capacitor's ESR determine the amplitude of the high-frequency ripple seen on the output voltage. For stability, the boost output-filter capacitor should have a value of  $10\mu$ F or greater when using 2.1MHz switching.

To avoid a large drop on HVINP when AVDD is enabled, the capacitance on the HVINP node should be at least three times larger than that on AVDD.

#### **Boost Input Filter Capacitor**

Sufficient input capacitance must be used to avoid input voltage drop when transients are encountered on the AVDD or NAVDD outputs and when the AVDD switch is closed. If the IN voltage drops below 2.57V, the device is likely to reset so input capacitance must prevent this. The total value of capacitance depends on the expected transients and the series resistance in the IN connection. A good starting point is a total input capacitance of  $2 \times 22\mu$ F ceramic capacitors in parallel with  $2 \times 10\mu$ F ceramic capacitors. Depending on the particular application circumstances more or less capacitance may be needed.

Input capacitance requirements are significantly relaxed when an input voltage of 5V is used.

#### Setting the AVDD Voltage

The AVDD output voltage is set by writing a 6-bit value to the AVDD\_SET register.

The NAVDD converter outputs a negative voltage whose absolute value is the same as AVDD.

#### NAVDD Inverting Regulator

#### NAVDD Regulator Inductor Selection

The inductor value for the NEG regulator can be selected using the formula below.

$$L = \frac{V_{\text{NAVDD}} \times (1 - D)}{\text{LIR} \times I_{\text{NAVDD}} \times f_{\text{SW}}}$$

where  $V_{NAVDD}$  is the output voltage,  $I_{NAVDD}$  the output current, LIR the desired inductor ripple ratio, and  $f_{SW}$  the switching frequency.

Calculate the duty-cycle D using:

 $D = \frac{V_{\rm NAVDD}}{V_{\rm IN} + V_{\rm NAVDD}}$ 

The inductor's saturation current rating must exceed the maximum current-limit of 2.25A.

#### **NAVDD External Diode Selection**

Select a diode with a peak current rating of at least the LXN current limit ( $I_{LIMNH}$ ) for use with the NAVDD output. The diode breakdown-voltage rating should exceed the sum of the maximum INN voltage and the absolute value of the NAVDD voltage. A Schottky diode improves the overall efficiency of the converter but should be selected to have low leakage at the maximum operating temperature.

#### NAVDD Output Capacitor Selection

The primary criterion for selecting the output filter capacitor is low ESR and capacitance value, as the NAVDD capacitor provides the load current when the internal switch is on. The voltage ripple on the NAVDD output has two components:

- 1. Ripple to due ESR which is the product of the peak inductor current and the output filter capacitor's ESR
- 2. Ripple due to bulk capacitance that can be determined as follows.

$$r = \frac{I_{\rm NAVDD} \times \frac{D}{f_{\rm SW}}}{I_{\rm SW}}$$

 $\Delta V_{BULK} = \frac{C}{C_{NAVDD}}$ 

For stability, the NAVDD output capacitor should have a value of 10µF or greater when using 2.1MHz switching frequency.

#### Setting the VGON and VGOFF Output Voltages

The internal positive charge pump can output a voltage approximately three times AVDD. If a voltage of twice the HVINP voltage is sufficient leave the FC1+ and FC1- pins unconnected and set the cp\_2stage bit.

For V<sub>GOFF</sub>, the number of charge-pump stages should be chosen to ensure sufficient output voltage while maintaining the VG<sub>OFF</sub> voltage within its permitted operating range.

The VG<sub>ON</sub> output voltage is set by writing a 6-bit value to the vgon[5:0] field in the VG<sub>ON</sub> register.

The VG<sub>OFF</sub> voltage is set by writing a 6-bit value to the vgoff[5:0] field in the VG<sub>OFF</sub> register.

#### VG<sub>ON</sub> Voltage Higher than Three Times AVDD

In exceptional cases, it may be necessary to produce a VG<sub>ON</sub> voltage greater than three times AVDD. In such cases, an external charge-pump circuit can be used as shown in Figure 4. When using the device in this way, leave the FC1-, FC1+ and FC2+ pins unconnected and set the cp\_2stage bit to 1.

#### 4x Charge Pump



Figure 4. Quadrupler Charge-Pump at 2.1MHz

#### VCOM Block

#### **VCB** Transistor

Select an external npn transistor with a minimum current gain of 30. When designing the PCB, ensure that the parasitic capacitance between the base and collector of the npn is minimized to avoid oscillation. Note that high continuous DC current on VCOM causes very high power dissipation in the npn device and a device with low thermal resistance should therefore be selected.

#### VCOM Temperature Compensation Example

Assume that an NTC with 10k $\Omega$  resistance at 25°C is connected from TEMP to GND and that the R<sub>REF</sub> resistor is of value 2400 $\Omega$ . At various temperatures, the following voltages will be observed on R<sub>REF</sub> and the ADC measurement result will be as follows:

TEMPERATURE	NTC RESISTANCE	R <sub>REF</sub> VOLTAGE	ADC RESULT	DESIRED VCOM VOLTAGE
-30°C	113kΩ	13mV	0x02	-1.09V
25°C	10kΩ	150mV	0x1F	-1V
60°C	3kΩ	500mV	0x66	-0.98V
85°C	1.5kΩ	1V	0xCD	-0.91V

#### Table 6. ADC Result vs Temperature

The rightmost column of the previous table indicates the desired VCOM output voltage at each temperature, which will be the inflection points in the temperature compensation curve. The following values are written to the relevant registers (remembering that each LSB of the VCOM setting represents 6.83mV):

### Table 7. VCOM Setting Example

REGISTER	FIELD	SETTING	NOTES
DELAYVCOM_LSB[7:0]	vcom25_0	0	0 bit value is 011011010 or 0xDA which corresponds to $1V$
VCOM25	vcom25[7:0]	0x6D	
VCOM_L	vcom_l[4:0]	0x0D	Represents shift of -89mV from VCOM25

## Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### Table 7. VCOM Setting Example (continued)

VCOM_H1	vcom_h1[4:0]	0x03	Represents shift of +20mV from VCOM25
VCOM_H2	vcom_h2[4:0]	0x0A	Represents shift of +68mV from VCOM_H1
VTEMP25	vtemp25[7:0]	0x1F	ADC result at 25°C
VTEMP_L	vtemp_I[7:0]	0x02	ADC result at -30°C
VTEMP_H1	vtemp_h1[7:0]	0x66	ADC result at 60°C
VTEMP_H2	vtemp_h2[7:0]	0xCD	ADC result at 85°C

With these settings, the VCOM output voltage at 25°C is -1V, while at the temperature represented by 13mV at the R<sub>REF</sub> pin the VCOM voltage decreases to -1.09V as set by the VCOM\_L register. Similarly, the VCOM\_H1 and VCOM\_H2 values are output on VCOM when the TEMP voltage is 500mV and 1V, respectively. In between these values the device interpolates the correct VCOM voltage value with a resolution of 6.83mV. The complete curve is shown in Figure 5.

When setting the values VTEMP\_xx and VCOM\_xx, it is important to avoid values which can cause wraparound in the temperature compensation algorithm thus possibly leading to sudden changes in the value of VCOM.

#### Sample VCOM Temperature Compensation Curve



Figure 5. Sample VCOM Temperature Compensation Curve

#### Using the NV Memory

Follow the sequence below to perform non-volatile programming of the device when the auto-refresh function is not used:

- 1. Apply a voltage between 3.3V and 5V to the IN and INN pins with the device in I<sup>2</sup>C mode
- 2. Write the desired values to be stored in OTP to the registers from 0x07 to 0x15
- 3. Apply 8.5V to V<sub>PROG</sub>
- 4. Optionally wait to ensure the 8.5V at VPROG is stable
- 5. Send burn\_otp\_reg (write any value to 0x78) command. If parity is enabled ensure the overall parity is even by altering the final byte if necessary.
- 6. Wait 20ms
- 7. If the nv\_fit bit is 0, the write was successful, go to next step. If nv\_fit = 1, perform re-try (steps 5,6).

### Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

8. Send reboot\_otp (write any value to 0x79) command.

Special care is required when performing non-volatile programming with the auto-refresh feature enabled. In such cases follow the sequence below when at least one calibration has already been performed:

- 1. Apply a voltage between 3.3V and 5V to the IN and INN pins
- 2. Write the desired values to be stored in NV memory to the registers from 0x07 to 0x15 (keep auto-refresh bit disabled until here)
- 3. Enable the auto-refresh feature
- 4. Start polling one of the registers from 0x07 to 0x15 which has changed its value until that value gets refreshed to the older one (auto-refresh is active)
- 5. The following steps from #6 to #10 must be completed within 1s
- 6. Write the desired values to be stored in OTP to the registers from 0x07 to 0x15 (including auto-refresh bit).
- 7. Apply 8.5V to VPROG
- 8. Optionally wait to ensure the 8.5V at V<sub>PROG</sub> is stable
- 9. Send burn\_otp\_reg (write any value to 0x78) command. If parity is enabled ensure the overall parity is even by altering the final byte if necessary
- 10. Wait 20ms
- 11. If the nv\_flt bit is 0, the write was successful, go to next step. If nv\_flt = 1, perform retry from step 2.
- 12. Send reboot otp (write any value to 0x79) command

The non-volatile memory can be written to a total of 5 times.

#### Layout Considerations

The MAX25220/MAX25221/MAX25221B include high-frequency switching converters to generate the voltages for TFT-LCDs. Take proper care while laying out the circuit board to ensure correct operation. The switching-converter portions of the circuit have nodes with very fast voltage changes that could lead to undesirable effects on the sensitive parts of the circuit as well as electromagnetic interference (EMI). Follow the guidelines below to reduce noise as much as possible:

- Connect the bypass capacitors on IN and INN as close as possible to the device and connect the capacitor ground to
  the analog ground plane using vias close to the capacitor terminal. Ensure that the power connection to IN and INN
  uses a very wide trace or complete board layer to avoid input undervoltage problems.
- Connect the GND pin of the device to the analog ground plane using a via close to GND. Lay the analog ground plane on the inner layer, preferably next to the top layer. Use the analog ground plane to cover the entire area under critical signal components for the power converter.
- Have a power-ground plane for the switching-converter power circuit under the power components (i.e., input filter capacitor, output filter capacitor, inductor, MOSFET, rectifier diode, and current-sense resistor). Connect PGND to the power-ground plane closest to PGND. Connect all other ground connections to the power ground plane using vias close to the terminals.
- Minimize the copper area of all switching nodes to avoid EMI. Minimize the loop areas for the AVDD and NAVDD converters by placing all components close to the LXP and LXN pins. Place the input and output capacitor grounds close to each other. In the case of AVDD the input/output capacitor grounds should also connect directly to the PGND pin.
- Connect GND, CPGND and PGND at the exposed pad of the device.
- Refer to the MAX25220/MAX25221/MAX25221B evaluation kit (EV kit) data sheet for a sample layout.

In addition, when using an external NTC temperature sensor for temperature compensation connect the grounded end directly to the grounded end of the RREF resistor. This avoids possible differences in ground potential between different points on the circuit board.

### **Typical Application Circuits**

### MAX25220 Applications Diagram



### **Typical Application Circuits (continued)**

### **MAX25221 Applications Diagram**



# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Ordering Information**

PART NUMBER	TEMPERATURE RANGE	PIN-PACKAGE	FEATURES
MAX25220ATJ/V+	-40 to +125°C	32 TQFN-EP	Without VCOM buffer
MAX25221ATJ/V+	-40 to +125°C	32 TQFN-EP	With VCOM buffer
MAX25220ATJ/VY+	-40 to +125°C	32 SWTQFN-EP	Without VCOM buffer
MAX25221ATJ/VY+*	-40 to +125°C	32 SWTQFN-EP	With VCOM buffer
MAX25221BATJ/V+	-40 to +125°C	32 TQFN-EP	EN pin turn-on, VCOM buffer

+ Denotes a lead(Pb)-free/RoHS-compliant package.

N denotes an automotive qualified part.

Y = Side-wettable package.

T Denotes tape-and-reel.

\*Future product - contact factory for availability.

# Automotive 4-Channel TFT-LCD Power Supply with VCOM Buffer

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	5/20	Initial release	—
1	6/20	Removed future product notation from MAX25221ATJ/V+ in Ordering Information	54
2	6/20	Added Typical Operating Characteristics	14, 15
3	10/20	Updated <u>Package Information</u> and <u>Electrical Characteristics</u> ; removed future product notation for MAX25220ATJ/VY+ in <u>Ordering Information</u>	7, 11, 54
4	11/20	Updated Pin Descriptions and Ordering Information.	19, 54

For pricing, delivery, and ordering information, please visit Maxim Integrated's online storefront at https://www.maximintegrated.com/en/storefront/storefront.html.

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